

# Optimizations of preparative parameters in potentiodynamic synthesis of cobalt oxide thin films: Capacitive approach

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The present article reports synthesis of  $\text{Co}_3\text{O}_4$  thin films by facile potentiodynamic-electrodeposition technique using variations in the preparative parameters such as ingredient, solution concentration and deposition time. The prepared samples were analysed using XRD, FE-SEM, TEM, cyclic voltammetry, chronopotentiometry and electrochemical impedance spectroscopy. Crystallographic study shows polycrystalline face centered cubic spinel structure of the deposit. Cyclic voltammogram reveals pseudocapacitive behavior. The calculated highest value of specific capacitance at the scan rate 5 mV/s was 237.68 F/g in 1 M KOH, within the potential window -0.92 to 0.45 V versus Ag/AgCl. The calculated maximum value of specific energy, specific power and columbic efficiency from chronopotentiometry were 4.91 Wh/kg, 28.69 kW/kg and 94.78%, respectively. The internal resistance observed using electrochemical impedance spectroscopy was ~ 3.55  $\Omega$ .

**Keywords:** Potentiodynamic electrodeposition, Cobalt oxide, Supercapacitor electrode, Cyclic voltammogram, Impedance

## 1 Introduction

Currently energy production and storage are the most imperative issues for the economic and industrial development. The most promising source of clean energy is sunlight acting in a sustainable way. Since solar energy is one of the sustainable and clean source of energy, tremendous amount of work is going on now-a-days to convert solar energy into chemical energy by generation of hydrogen as a fuel<sup>1,2</sup> and solar energy into electrical energy photovoltaic devices<sup>3,4</sup>. On the other hand, the energy storage devices, such as rechargeable small-sized ion batteries<sup>5,6</sup> have also been preferred. Among several kinds of energy storage devices, electrochemical capacitors/supercapacitors (SCs) became noticeable because of their high energy density, high energy efficiency and long charge-discharge cycle life<sup>7</sup>. The SCs are categorized into two types based on charge storage mechanism, one is electrochemical double layer capacitors (EDLCs), *i.e.*, non-faradaic and the second is pseudocapacitors or faradaic capacitors<sup>8,9</sup>. SCs possess higher power density and more rapid charge-discharge rate as compared to conventional batteries<sup>10,11</sup>. Nevertheless, a lower amount of energy density and life-times of SCs, in contrast with rechargeable batteries, are two key challenges for scientists. Researchers are trying to increase the energy, power density and stability of the

pristine materials. To achieve these targets, researchers have turned their attention in the past few years towards different morphology dependent materials like transition metal oxides (TMOs) such as ruthenium (IV) oxide<sup>12</sup>, manganese dioxide<sup>13-15</sup>, cobalt oxide/hydroxide<sup>16-19</sup>, nickel(II)oxide/hydroxide<sup>20-22</sup>,  $\text{Fe}_3\text{O}_4$ <sup>23</sup> etc. as electrode in supercapacitor. Among these metal oxides, cobalt oxide based electrode showed different morphologies with improvement in the supercapacitive performance and posse's 3500 F/g maximum value of theoretical capacitance<sup>24-26</sup>. Recent study reports  $\text{Co}_3\text{O}_4$  nanostructures with various morphologies including nano-particles<sup>27</sup>, nanowires<sup>28,29</sup>, nanotubes<sup>30</sup> and nano-sheets<sup>31</sup> which have been successfully synthesized by changing preparative parameters and methods in order to improve the super capacitive properties.

Intention of present study is to check the improvement in the capacitive performances of pristine cobalt oxide thin film electrodes by varying different cobalt ingredients, molar concentrations of the optimized ingredient solution and deposition time of the electrode.

## 2 Experimental Details

### 2.1 Materials and methods

All the chemicals used during the synthesis are of analytical grade, purchased from Sigma Aldrich chemicals and are used without any further purification. Template-free, binder-less cobalt

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hydroxide layers were potentiodynamically electrodeposited on well cleaned stainless steel (SS) substrates (no. 304,  $1 \times 5 \text{ cm}^2$ ) using conventional three-electrode cell configuration. Here the platinum was used as a counter electrode and Ag/AgCl was used as a reference electrode. Computer controlled potentiostat (CHI 600 D Electrochemical Analyzer/workstation, CH instruments, USA) was used to carry the potentiodynamic electrodeposition. Prior to the deposition, 0.1M solutions were prepared in double distilled water using different ingredients like cobaltous chloride hexa-hydrate ( $\text{CoCl}_2 \cdot 6\text{H}_2\text{O}$ ), cobaltous nitrate hexa-hydrate ( $\text{Co}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$ ), cobaltous acetate tetra-hydrate ( $\text{C}_4\text{H}_6\text{CoO}_4 \cdot 4\text{H}_2\text{O}$ ). The SS substrates were etched prior to each experiment using a diluted hydrochloric acid (Merck, 60%) for 1 min and finally washed and ultrasonically cleaned with double distilled water. During the deposition, deposition potential window, deposition scan rate and deposition time was maintained as -1.0 V to -0.1 V, 100 mV/s and 30 min, respectively. Further, the samples were deposited for different molar concentrations and deposition times. The deposited samples were annealed at 300 °C for 1.5 h for complete conversion of cobalt hydroxide to cobalt oxide ( $\text{Co}_3\text{O}_4$ ).

The obtained  $\text{Co}_3\text{O}_4$  samples were nomenclature as; for ingredients: cobalt chloride- A, cobalt nitrate- B and cobalt acetate- C, for molar concentration variation:  $M_1$ : 0.05M,  $M_2$ : 0.1M,  $M_3$ : 0.15M,  $M_4$ : 0.2M,  $M_5$ : 0.25M,  $M_6$ : 0.3M and for deposition time variation  $D_1$ : 20 min,  $D_2$ : 30 min,  $D_3$ : 40 min,  $D_4$ : 50 min and  $D_5$ : 60 min, respectively.

## 2.2 Characterizations

X-ray diffraction analysis was carried out using (Rigaku D/max 2550  $\text{Vb}^+/\text{PC}$  18 kW with  $\text{Cu } \alpha\lambda = 0.15405 \text{ nm}$ ) diffractometer by varying diffraction angle  $2\theta$  within the range of 20°-80°. Surface morphological analysis was performed by using field emission-scanning electron microscope (FE-SEM; MIRA3, TESCAN). Weight of the deposited materials was measured by weight difference method using ultrasensitive, high accuracy analytical microbalance (Tapson's Model 6-100 TS). Electrochemical supercapacitive behavior of the prepared electrodes was carried out using computer controlled potentiostat (CHI600D electrochemical analyzer/workstation, CH instruments USA) with standard three electrodes cell configuration. Here the prepared  $\text{Co}_3\text{O}_4$  electrodes were used as the working electrodes, platinum as a counter electrode and saturated Ag/AgCl as a reference

electrode. The cyclic voltammetry (CV) was carried out within the potential window of -0.92 to 0.45 V in 1 M KOH at the scan rate of 5 mV/s for each electrode. Charge-discharge behavior of the prepared electrodes was studied at different current densities using chronopotentiometry. Multi frequency impedance measurements were made in the frequency range 1 mHz to 1 MHz using AC signal with open circuit potential (OCP) at -0.38 V applied with 5 mV amplitude. Electrochemical impedance spectroscopy (EIS) data was fitted with standard data to search an equivalent circuit and parameters using ZsimpWin software.

## 2.3 Electrochemical measurements

From the CV curves, SC (Specific capacitance) values were calculated using the following equations<sup>32</sup>:

$$C = \frac{\int Idt}{dv/dt} \quad \dots (1)$$

$$SC = C/w \quad \dots (2)$$

where,  $\int Idt$  is the area under curve,  $\frac{dv}{dt}$  is the

voltage scan rate,  $C$  is the capacitance,  $w$  is the weight of the active material dipped in electrolyte.

The specific energy (SE), specific power (SP) and columbic efficiency  $\eta$  (%) were estimated using the following relations.

$$SE = (V \times I_d \times t_d)/w \quad \dots (3)$$

$$SP = (V \times I_d)/w \quad \dots (4)$$

$$\eta = (t_c \times 100)/w \quad \dots (5)$$

Where,  $t_c$  and  $t_d$  represent the time of charge and discharge,  $I$  is the current density and  $V$  is the applied voltage.  $w$  is the active weight of the sample dipped in the electrolyte.

## 3 Results and Discussion

### 3.1 Film formation mechanism

The cobalt oxide thin films were potentiodynamically electrodeposited from the three different ingredients; cobalt chloride (A), cobalt nitrate (B) and cobalt acetate (C) onto the SS substrate. During electrodeposition, the cobalt ions or complexes were hydrolyzed by aqueous solution to form the hydroxide deposits on the working electrode. After annealing at 300 °C for 1.5 h, the  $\text{CoO}(\text{OH})$  was converted into  $\text{Co}_3\text{O}_4$ .

### 3.2 Film thickness

Thickness of different molar samples were calculated by gravimetric weight difference method using the relation  $t=m/(\rho \times A)$ ; where,  $m$  is the active mass in milligram,  $A$  is the active area ( $\text{cm}^2$ ) and  $\rho$  is the density of the deposited material which is assumed to be the same as that of the bulk material ( $\rho = 6.11 \text{ g/cm}^3$  for  $\text{Co}_3\text{O}_4$ ). Figure 1 shows the variation of film thickness with solution concentration (M). From the figure it was observed that with increase in solution concentration, film thickness goes on increasing and it finally becomes stable beyond  $M_6$ . The rate of film thickness was not found linear with solution concentration. The stable value of film thickness was observed at higher concentration because of pilling out of film due to the increase of tensile stress that causes delamination when film becomes thick<sup>33,34</sup>.

### 3.3 Structural analysis

The XRD patterns were studied to get crystallographic information, orientation of the planes for all the prepared samples. Figure 2(a-c) shows XRD patterns of the samples prepared by using different cobalt ingredients (A, B and C), different molar concentration ( $M_1, M_2, M_4$  and  $M_6$ ) and different deposition time interval ( $D_1, D_2, D_3$  and  $D_5$ ), respectively. Compared with the standard data (JCPDS, Card No. 80-1545), characteristic peaks appearing at  $2\theta=30.9^\circ, 36.4^\circ, 44.3^\circ, 48.5^\circ, 55^\circ, 58.6^\circ, 67.8^\circ, 68.9^\circ, 77.4^\circ$  corresponding to the crystal faces (220), (311), (400), (331), (422) (511), (440), (442) and (622), respectively, confirms the face centered cubic crystal structure of  $\text{Co}_3\text{O}_4$  electrodes. The peaks

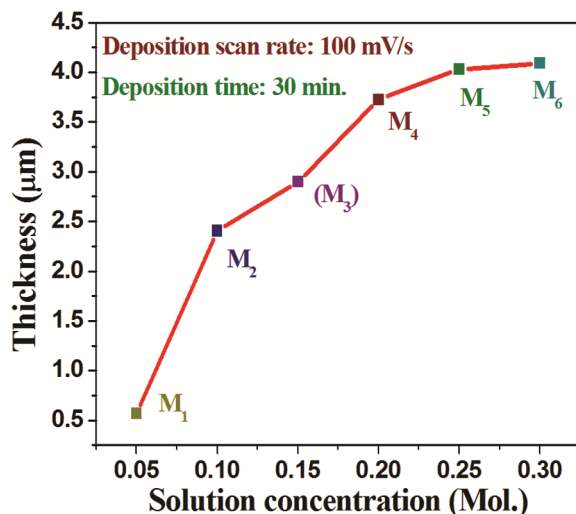


Fig. 1 — Variation of film thickness ( $\mu\text{m}$ ) with solution concentrations (mol.) of  $\text{Co}_3\text{O}_4$ .

marked by asterisk belong to stainless steel substrate. It was observed that all the diffraction peaks of  $\text{Co}_3\text{O}_4$  are broad and the intensity of certain peaks is comparatively weak, which indicate that the obtained material is poorly crystallized<sup>35</sup>. The similar trend was

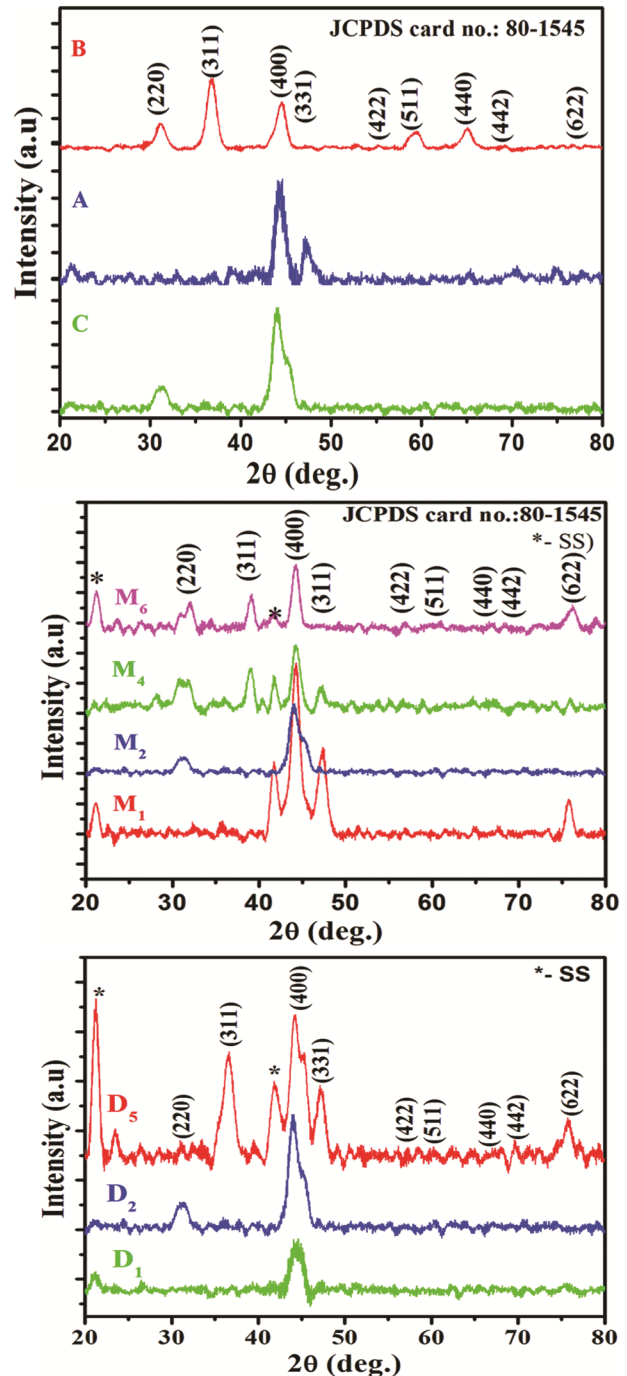


Fig. 2 — (a) XRD pattern of  $\text{Co}_3\text{O}_4$  samples A, B and C prepared using different cobalt ingredients and (b) XRD pattern of  $\text{Co}_3\text{O}_4$  samples  $M_1, M_2, M_4$  and  $M_6$  prepared using different solution concentration.

observed for the different molar concentration and also for samples deposited at different time intervals.

### 3.4 Morphological evolution

The morphological evolution of all the prepared samples were observed using FE-SEM images. Figure 3 (A<sub>1</sub>-A<sub>2</sub>, B<sub>1</sub>-B<sub>2</sub> and C<sub>1</sub>-C<sub>2</sub>) shows the FE-SEM images of cobalt oxide samples, A, B and C, respectively. The micrograph obtained from sample A (Fig. 3 (A<sub>1</sub>-A<sub>2</sub>)) shows uniformly distributed granular type of morphology. Inset of figure shows magnified view of the sample clearly indicate porous nature. Similar type of morphology was observed earlier for cobalt oxide prepared by SILAR, which was feasible for supercapacitor application, as it may offer increased surface area<sup>36,37</sup>. The sample B shows interconnected nanoflake type of morphology, whereas the sample C shows randomly distributed nanoflake like

morphology, which was consistent with the previous results, obtained using electrodeposition technique<sup>39</sup>. These variations in the morphology of the samples A, B and C may be attributed due to the influence of the over-potential of the anions Cl<sup>-</sup>, NO<sub>3</sub><sup>-</sup> and CH<sub>3</sub>COO<sup>-</sup> present in the precursors<sup>20,39,40</sup>.

Figure 4 (a-d) is the typical FE-SEM images of samples for varied concentration M<sub>2</sub> (0.1M) and sample M<sub>6</sub> (0.3M). The FE-SEM micrograph images (Fig. 4 (a,b)) of sample M<sub>2</sub> clearly shows agglomeration of grains type morphology. While, for sample M<sub>6</sub> the micrograph images (Fig. 4 (c-d)) shows highly agglomerated granular type of morphology. It may concluded that, initially grown nano-grains may have increased their particle size for further deposition and particles come close to each other with increase in solution concentration.

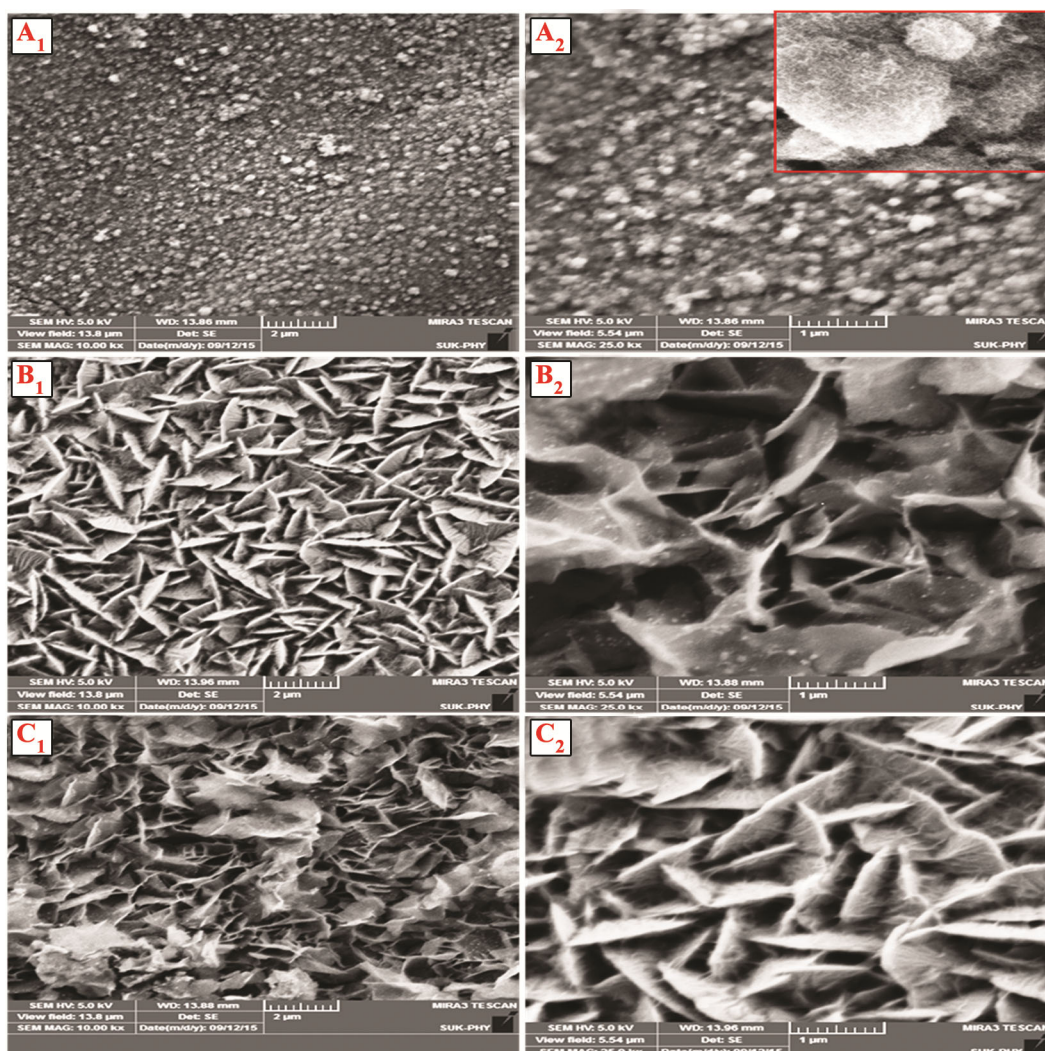


Fig. 3 — FE-SEM images of Co<sub>3</sub>O<sub>4</sub> of different ingredients A, B and C at various magnifications. Inset of the figure shows magnified view.

Figure 5 shows FE-SEM images of typical  $D_2$  (30 min) and  $D_5$  (60 min)  $Co_3O_4$  samples. It was observed that morphology of sample  $D_2$  shows structural

homogeneity and uniformity, which consists of fully covered-agglomerated granular particles. However as the deposition time was increased to  $D_5$ , agglomeration

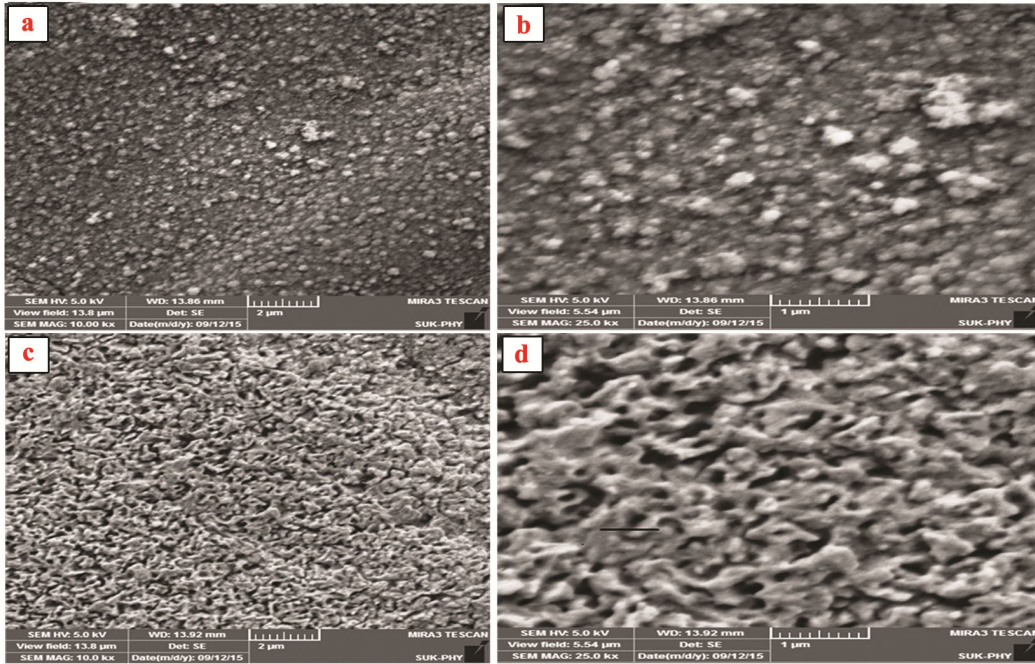


Fig. 4 — FE-SEM images of  $Co_3O_4$  prepared using cobalt chloride as a ingredient, sample  $M_2$  (a and b) and sample  $M_6$  (c and d) at 10000 and 25000 magnifications.

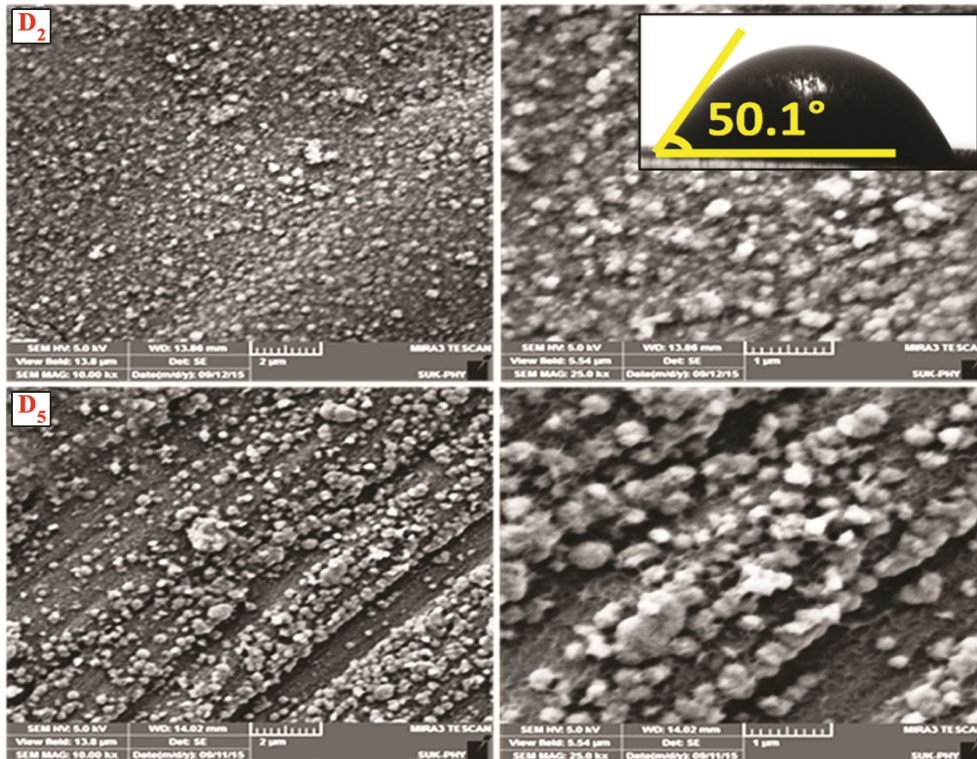


Fig. 5 — FE-SEM images of  $Co_3O_4$  of sample  $M_2$  carried for different deposition times. Inset of Figure shows wettability of the sample.

of the granular particles resulted into the discontinuous distribution of larger grains, which may decrease the active surface area of the electrodes.

Behavior of the liquid with the sample plays prominent role in supercapacitor performance. So wettability test was carried out for sample D<sub>2</sub>. If the wettability is high, contact angle ( $\theta$ ) will be small and the surface is hydrophilic. If the wettability is low, contact angle ( $\theta$ ) will be large and the surface is hydrophobic. Inset of Fig. 5 depicts the contact angle measurement. Measured contact angle was about 50.1° clearly indicating hydrophilic nature of the deposit. It was earlier reported that hydrophilic surface of the electrode is an essential factor for better performance of electrochemical supercapacitor<sup>41</sup>.

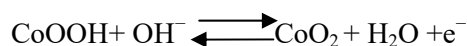
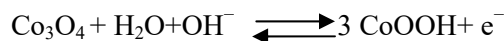
### 3.5 TEM analysis

Further, micro-structural analysis of typical cobalt oxide (Co<sub>3</sub>O<sub>4</sub>) thin film sample (D<sub>2</sub>) was investigated using the TEM image. TEM analysis (Fig. 6) reveals that material shows granular agglomerated microstructure with porous nature of the particles. The obtained average value of particle size was around 100 nm.

### 3.6 Electrochemical studies

#### 3.6.1 Cyclic voltammetry

Cyclic voltammograms were carried to observe the electrochemical performance of all the prepared samples. Figure 7 (a) shows the typical CVs of the cobalt oxide electrodes A, B and C carried at scan rate 5 mV/s in 1 M KOH within the potential window - 0.92 to 0.45 V. All CVs show pseudocapacitive behavior. Two noticeable pairs of redox peaks are observed in the CV which corresponded to the conversion between different cobalt oxidation states according to the following reactions.



The first reaction reflects the conversion between Co(II) to Co(III) for the first redox couple. The second reaction reflects the conversion between Co(III) to Co(IV) for the second redox couple<sup>42</sup>. These redox couples confirm the pseudocapacitive nature of the prepared electrode. Here electrode (A) obtained for chloride precursors shows the maximum area under the curve, whereas for electrode (B) and (C) obtained from nitrate and acetate precursors shows decrease in redox peaks and less area under curve. The calculated maximum value of specific capacitance for electrode (A) was 237.68 F/g, 102.03 F/g for electrode (B) and 59.91 F/g for electrode (C). Figure 7 (b) represents the CV's of cobalt oxide electrode prepared using different solution concentration variation for optimized ingredient cobalt chloride (A). CV's of all the electrodes were carried out at scan rate 5 mV/s in 1 M KOH within the potential window - 0.92 to 0.45 V. From the CV curve it is clearly observed that sample M<sub>2</sub> shows maximum area under the curve and with large redox peaks, electrode M<sub>1</sub> to M<sub>6</sub> shows decrease in area under curve and redox peaks. The SC associated with the electrode was calculated for various electrodes. The maximum SC value 237.68 F/g was obtained for electrode M<sub>2</sub>. Corresponding SC values are 204.91 F/g, 237.68 F/g, 157.82 F/g, 118.58 F/g, 95.62 F/g and 87.64 F/g for M<sub>1</sub>, M<sub>2</sub>, M<sub>3</sub>, M<sub>4</sub>, M<sub>5</sub> and M<sub>6</sub>, respectively. The redox peaks may occur due to the charge transfer process between electrode and electrolyte. Extraction of ions and electrons from the film is associated with the oxidation peaks, whereas

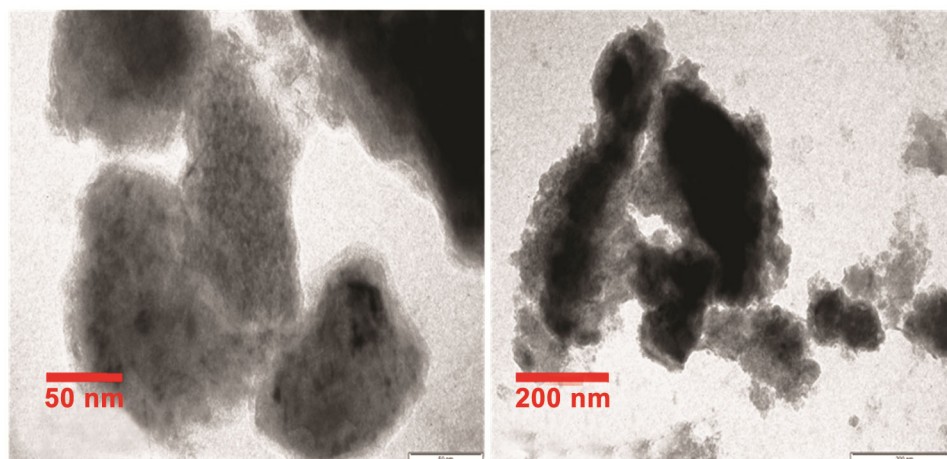


Fig. 6 — TEM image of D<sub>2</sub> sample.

insertion of ions and electrons into the film is associated with the reduction peaks<sup>43</sup>.

Figure 7 (c) shows CVs of typical electrodes D<sub>2</sub>, D<sub>3</sub> and D<sub>5</sub> carried out at the scan rate 5 mV/s in 1 M KOH in potential range - 0.92 to 0.45 V. All CV shows

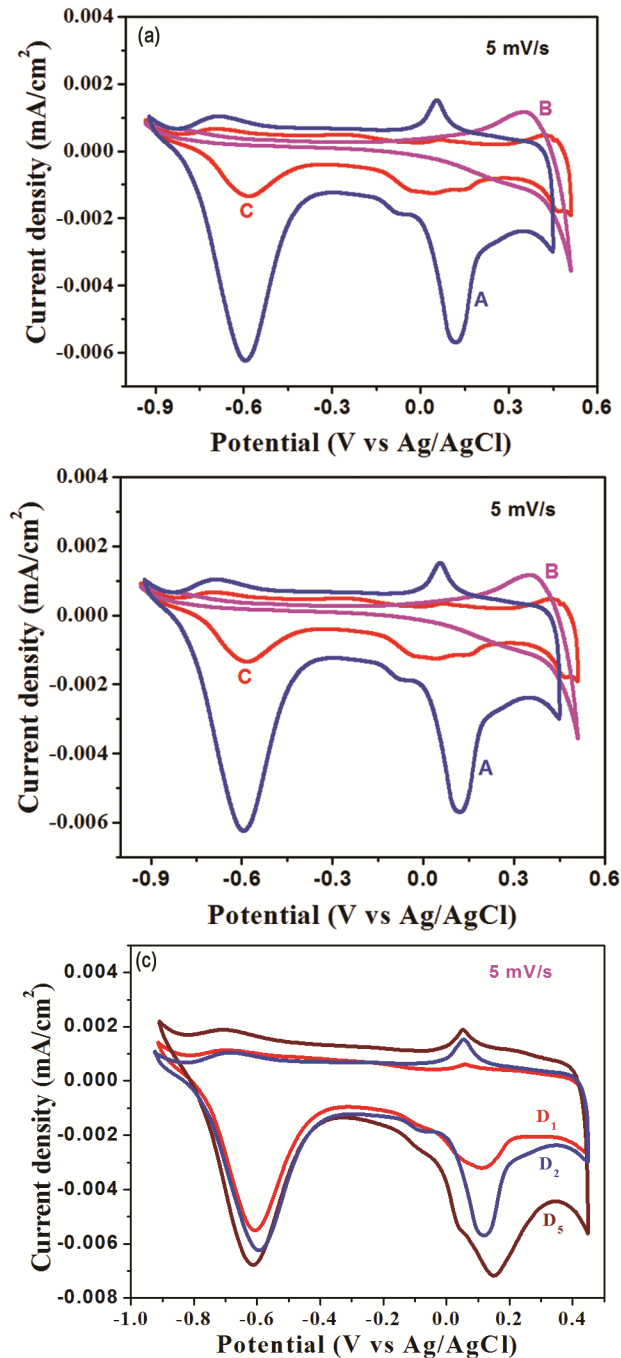


Fig.7 — (a) Cyclic voltammogram of electrodes A, B and C carried at scan rate 5 mV/s in 1M KOH, (b) cyclic voltammogram of electrode M<sub>1</sub>, M<sub>2</sub>, M<sub>3</sub>, M<sub>4</sub>, M<sub>5</sub> and M<sub>6</sub> carried at 5 mV/sec in 1 M KOH and (c) cyclic voltammogram of electrode D<sub>2</sub>, D<sub>3</sub> and D<sub>5</sub> carried at 5 mV/s in 1 M KOH.

mixed-capacitive nature with redox peaks at the respective anodic and cathodic sweeps. It can be observed from the CV that D<sub>5</sub> electrode shows large area under curve, current density, electrode D<sub>2</sub> shows less area under curve compared to D<sub>5</sub> and D<sub>1</sub> shows less area under curve and current density. The calculated value of SC for D<sub>1</sub> electrode was 177.83 F/g, D<sub>2</sub> is 237.68 F/g and D<sub>5</sub> is 159.95 F/g. Electrode D<sub>2</sub> shows maximum value of SC as compared to other electrodes. This may be attributed to the uniform growth of granular type of morphology of the film as compared to other films. However, though the sample D<sub>5</sub> shows larger current density, weight of the deposited active material is much larger due to longer deposition time interval which effect on the electrochemical performance of the D<sub>5</sub>.

### 3.6.2 Chronopotentiometry

Figure 8 shows charge-discharge behavior of M<sub>2</sub> electrode scanned in 1 M KOH for different current densities like 5, 10, 15, 25 and 40 mA/cm<sup>2</sup>. Here it was observed that with increase in current density, charge discharge curves shifts towards symmetric nature. In point of fact at 15 mA/cm<sup>2</sup> current density, electrode shows nearly symmetric charge-discharge behaviour as compared to others which indicates nearly rectangular nature of the CV curve (*i.e.*, ideal behaviour). The linear decrease in the potential drop (ohmic drop) observed at lower current density itself indicates the pseudocapacitive behavior of the prepared electrode. The electrical parameter such as SE, SP and  $\eta$  were calculated from charge-discharge curves using the relations (3) to (5). The calculated value of SE, SP and  $\eta$  are given in Table 1. The highest calculated values of SE, SP and  $\eta$  were 4.91 Wh/kg and 28.69 kW/kg and 94.78 %, respectively.

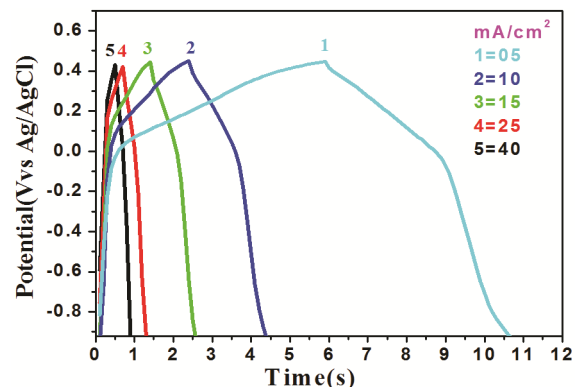


Fig. 8 — Charge-discharge curve of D<sub>2</sub> electrode carried at different current densities (mA/cm<sup>2</sup>).

Table 1 — SE, SP and  $\eta$  for the optimized electrode D<sub>2</sub>.

Current density (mA/cm <sup>2</sup> )	Specific energy (Wh/kg)	Specific power (kW/kg)	Efficiency (%)
5	4.91	3.58	66.82
10	3.94	7.17	68.32
15	3.14	10.75	65.47
20	3.14	14.34	87.6
25	2.99	17.93	86.84
30	3.00	21.51	83.20
35	2.82	25.10	80.99
40	3.15	28.69	94.78

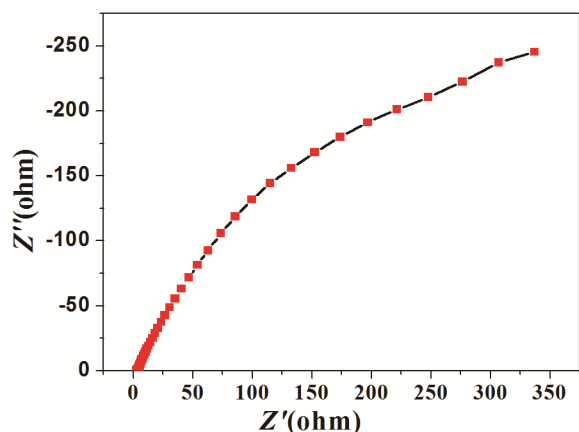


Fig. 9 — Nyquist plot of D<sub>2</sub> electrode.

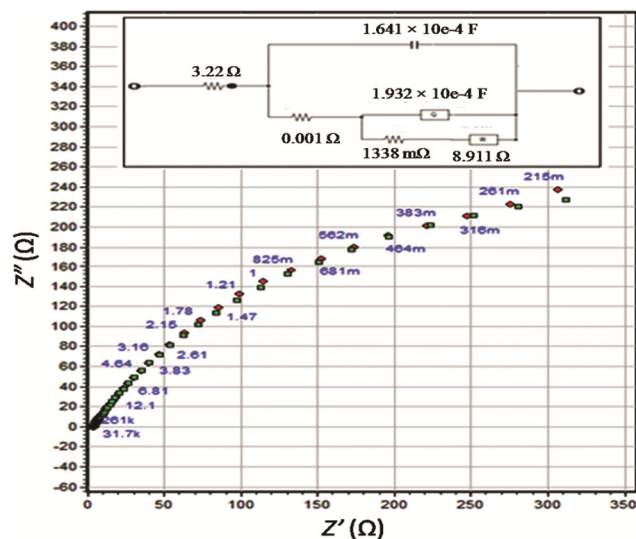


Fig. 10 — Matched Nyquist plot of D<sub>2</sub> electrode.

3.6.3 Electrochemical impedance spectroscopy

Using electrochemical impedance spectroscopy (EIS) technique, internal resistance and capacitive behavior of D<sub>2</sub> electrode was studied at operating open circuit potential (OCP) - 0.38 V in 1 M KOH in the frequency range of 1 mHz to 1 MHz. Figure 9 shows the Nyquist plot of ( $Z''$  vs  $Z'$ ) imaginary and real

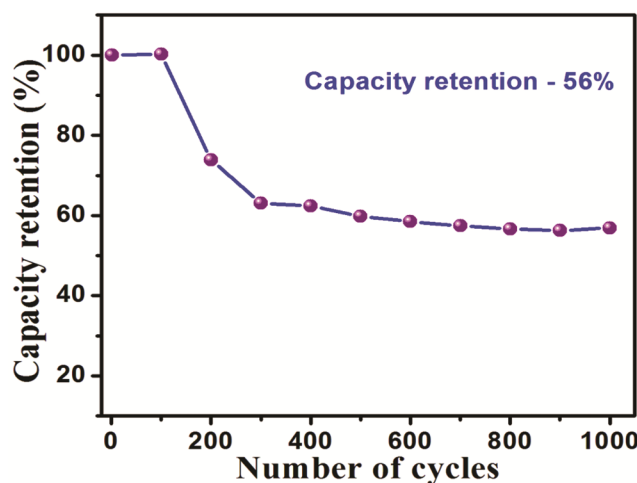


Fig. 11 — Stability curve of D<sub>2</sub> electrode carried at 100 mV/s.

impedance. Nyquist plot composed of three regions, at higher frequency region a depressed semicircle results from a parallel combination of the charge-transfer resistance ( $R_{ct}$ ) caused by the faradaic reactions at the lower frequency region. The observed internal resistance ( $R_i$ ) was around 3.56  $\Omega$ . Portion of the curve having an inclination of  $\sim 45^\circ$  with imaginary axis gives the value of warburg resistance ( $W$ ) and is related to the frequency dependent diffusion resistance of electrolyte ions resulted at the time of intercalation in pores of electrode. Figure 10 (Nyquist plot of  $Z''$  versus  $Z'$ ) shows the experimental and standard curves obtained by simulation using ZsimpWin software of Co<sub>3</sub>O<sub>4</sub> electrode and inset of it shows matched equivalent circuit. The observed circuitry parameters are capacitance  $C_1 = 1.641 \times 10^{-4}$  F, pseudocapacitance  $Q = 1.932 \times 10^{-4}$  F,  $R_1 = 3.22 \Omega$ ,  $R_2 = 0.001 \Omega$  and  $R_3 = 1338 \text{ m}\Omega$  and Warburg resistance  $W = 8.911 \Omega$ , respectively.

3.6.4 Stability

To know the durability of the prepared electrode, stability test was carried out at the scan rate of 100 mV/s in 1 M KOH up to 1000 cycles. Figure 11 shows stability test curve of D<sub>2</sub> electrode, which shows a stable value of SC after 500 cycles. The decrease in % capacitance was found to be 59%. This may be attributed to the degradation of active material for large cycle numbers within the electrolyte bath during the potential cycling at higher scan rate.

4 Conclusions

Co<sub>3</sub>O<sub>4</sub> electrodes were prepared successfully by template-free binder-less potentiodynamic electrodeposition technique. All the prepared samples



were characterized by XRD shows polycrystalline cubic face centered crystal structure. Different precursors give agglomerated grains, randomly distributed nanoflakes and interconnected nanoflakes like morphology confirmed by FE-SEM and TEM images. Solution concentration and deposition time optimization enhances morphology and the electrochemical performance. Electrochemical CV characterization indicates pseudocapacitive behavior. The maximum value of  $SC$  in 1 M KOH was 237.38 F/g. The obtained specific energy, specific power and columbic efficiency for the optimized electrode (0.1 M deposited for 30 min) were 4.91 Wh/kg, 28.69 kW/kg and 94.78%, respectively. EIS of complex impedance spectra shows internal resistance of 3.55  $\Omega$ .

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